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Team Nexperia

74AUP1G57

Low-power configurable multiple function gate

Rev. 7 — 16 September 2015

Product data sheet

1. General description

The 74AUP1G57 provides configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XNOR, inverter, and buffer. All inputs can be connected to V_{CC} or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74AUP1G57 has Schmitt trigger inputs making it capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H .

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 5000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from $-40\text{ }^{\circ}C$ to $+85\text{ }^{\circ}C$ and $-40\text{ }^{\circ}C$ to $+125\text{ }^{\circ}C$



3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G57GW	−40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1G57GM	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G57GF	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891
74AUP1G57GN	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G57GS	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G57GX	−40 °C to +125 °C	X2SON6	plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 × 0.8 × 0.35 mm	SOT1255

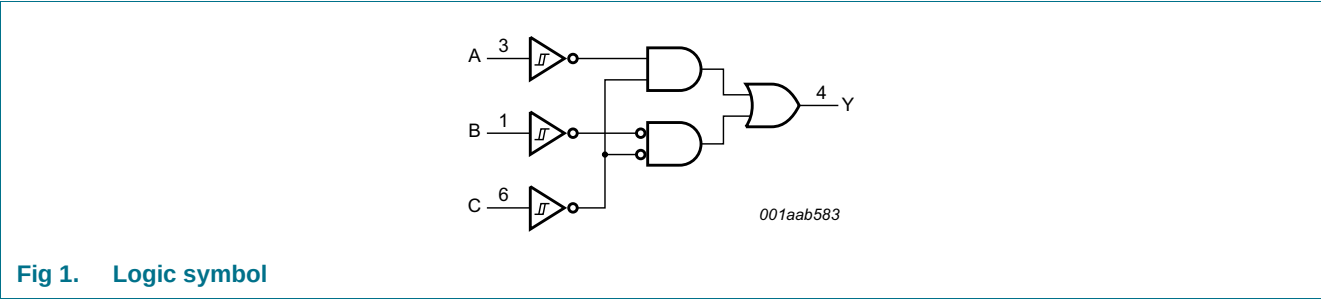
4. Marking

Table 2. Marking

Type number	Marking code ^[1]
74AUP1G57GW	aC
74AUP1G57GM	aC
74AUP1G57GF	aC
74AUP1G57GN	aC
74AUP1G57GS	aC
74AUP1G57GX	aC

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning

Fig 2. Pin configuration SOT363

Fig 3. Pin configuration SOT886

Fig 4. Pin configuration SOT891, SOT1115 and SOT1202

Fig 5. Pin configuration SOT1255 (X2SON6)

6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
B	1	data input
GND	2	ground (0 V)
A	3	data input
Y	4	data output
V _{CC}	5	supply voltage
C	6	data input

7. Functional description

Table 4. Function table^[1]

Input			Output
C	B	A	Y
L	L	L	H
L	L	H	L
L	H	L	H
L	H	H	L
H	L	L	L
H	L	H	L
H	H	L	H
H	H	H	H

[1] H = HIGH voltage level; L = LOW voltage level.

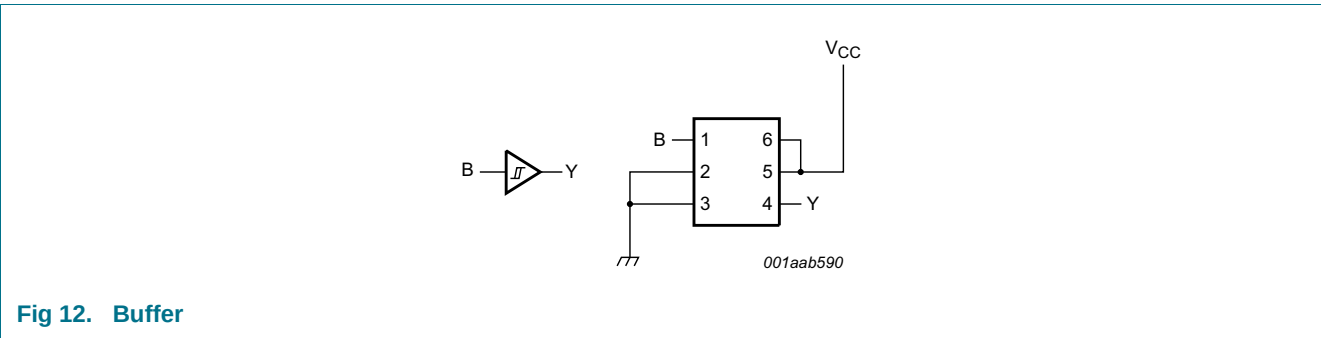
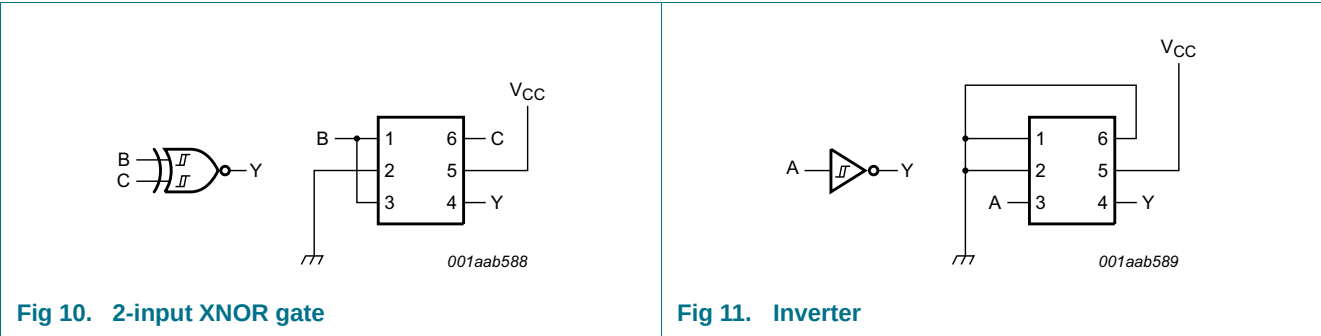
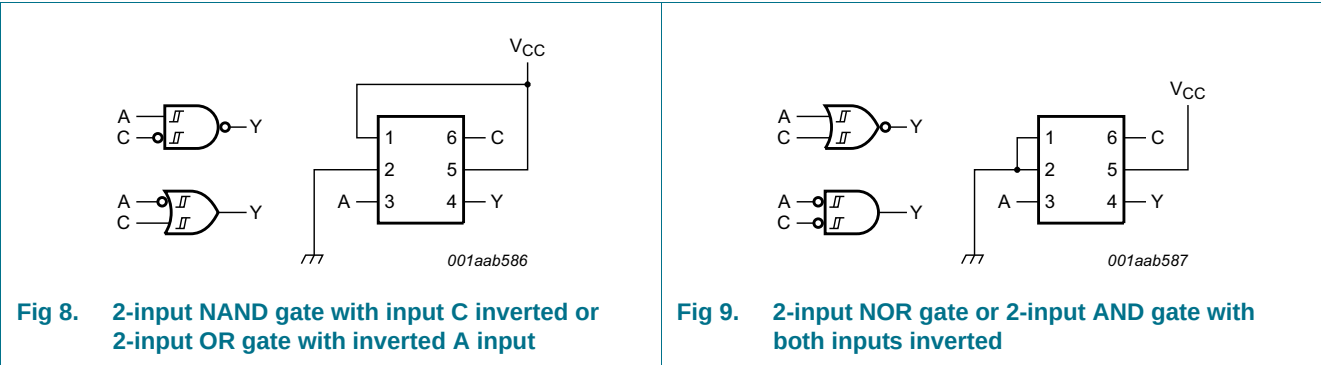
7.1 Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input AND	see Figure 6
2-input AND with both inputs inverted	see Figure 9
2-input NAND with inverted input	see Figure 7 and Figure 8
2-input OR with inverted input	see Figure 7 and Figure 8
2-input NOR	see Figure 9
2-input NOR with both inputs inverted	see Figure 6
2-input XNOR	see Figure 10
Inverter	see Figure 11
Buffer	see Figure 12

Fig 6. 2-input AND gate or 2-input NOR gate with both inputs inverted

Fig 7. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input



8. Limiting values

Table 6. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		−0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	−50	-	mA
V _I	input voltage	[1]	−0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	−50	-	mA
V _O	output voltage	Active mode and Power-down mode [1]	−0.5	+4.6	V
I _O	output current	V _O = 0 V to V _{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40\text{ °C to }+125\text{ °C}$ [2]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.For X2SON6 and XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
V_I	input voltage		0	3.6	V
V_O	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; $V_{CC} = 0\text{ V}$	0	3.6	V
T_{amb}	ambient temperature		-40	+125	°C

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25\text{ °C}$						
V_{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = -20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	$V_{CC} - 0.1$	-	-	V
		$I_O = -1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_O = -1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$	1.11	-	-	V
		$I_O = -1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$	1.32	-	-	V
		$I_O = -2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$	2.05	-	-	V
		$I_O = -3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$	1.9	-	-	V
		$I_O = -2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$	2.72	-	-	V
		$I_O = -4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$	2.6	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	0.1	V
		$I_O = 1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$	-	-	$0.3 \times V_{CC}$	V
		$I_O = 1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$	-	-	0.31	V
		$I_O = 1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$	-	-	0.31	V
		$I_O = 2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.31	V
		$I_O = 3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.44	V
		$I_O = 2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.31	V
		$I_O = 4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.44	V

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	40	μA
C _I	input capacitance	V _I = GND or V _{CC} ; V _{CC} = 0 V to 3.6 V	-	1.1	-	pF
C _O	output capacitance	V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
T _{amb} = –40 °C to +85 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T–}				
		I _O = –20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} – 0.1	-	-	V
		I _O = –1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = –1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = –1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = –2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = –3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = –2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = –4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T–}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	50	μA
T _{amb} = –40 °C to +125 °C						

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	µA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.75	µA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	µA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	1.4	µA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	75	µA

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 14](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C			Unit	
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)		
C _L = 5 pF										
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	22.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.8	6.5	12.6	2.5	13.0	13.2	ns
		V _{CC} = 1.4 V to 1.6 V		2.2	4.6	7.6	2.5	8.2	8.6	ns
		V _{CC} = 1.65 V to 1.95 V		2.1	3.9	6.2	2.0	6.8	7.2	ns
		V _{CC} = 2.3 V to 2.7 V		2.0	3.1	4.5	1.8	5.1	5.3	ns
		V _{CC} = 3.0 V to 3.6 V		1.8	2.8	3.9	1.5	4.1	4.3	ns
C _L = 10 pF										
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	26.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.2	7.3	14.4	2.8	14.9	15.2	ns
		V _{CC} = 1.4 V to 1.6 V		2.6	5.2	8.7	2.8	9.3	9.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.5	4.5	7.0	2.2	7.8	8.2	ns
		V _{CC} = 2.3 V to 2.7 V		2.4	3.7	5.2	2.1	5.9	6.2	ns
		V _{CC} = 3.0 V to 3.6 V		2.3	3.4	4.6	1.9	4.9	5.1	ns
C _L = 15 pF										
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	31.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.4	8.0	15.7	3.1	16.7	17.0	ns
		V _{CC} = 1.4 V to 1.6 V		2.8	5.7	9.4	3.1	10.4	10.9	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	4.9	7.7	2.5	8.7	9.2	ns
		V _{CC} = 2.3 V to 2.7 V		2.6	4.1	5.7	2.4	6.5	6.9	ns
		V _{CC} = 3.0 V to 3.6 V		2.5	3.8	5.0	2.2	5.5	5.7	ns

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 14](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +125 °C			Unit	
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)		
C _L = 30 pF										
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	37.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.6	10.4	20.9	3.9	21.8	22.3	ns
		V _{CC} = 1.4 V to 1.6 V		3.6	7.4	12.2	3.8	13.4	14.1	ns
		V _{CC} = 1.65 V to 1.95 V		3.5	6.2	9.9	3.1	11.1	11.8	ns
		V _{CC} = 2.3 V to 2.7 V		3.4	5.2	7.4	3.1	8.3	8.8	ns
		V _{CC} = 3.0 V to 3.6 V		3.2	4.9	6.6	2.8	7.0	7.4	ns
C _L = 5 pF, 10 pF, 15 pF and 30 pF										
C _{PD}	power dissipation capacitance	f _i = 1 MHz; V _I = GND to V _{CC}	[3][4]							
		V _{CC} = 0.8 V		-	2.6	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V		-	2.8	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V		-	2.9	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V		-	3.1	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V		-	3.7	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	4.3	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

[3] All specified values are the average typical values over all stated loads.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

12. Waveforms

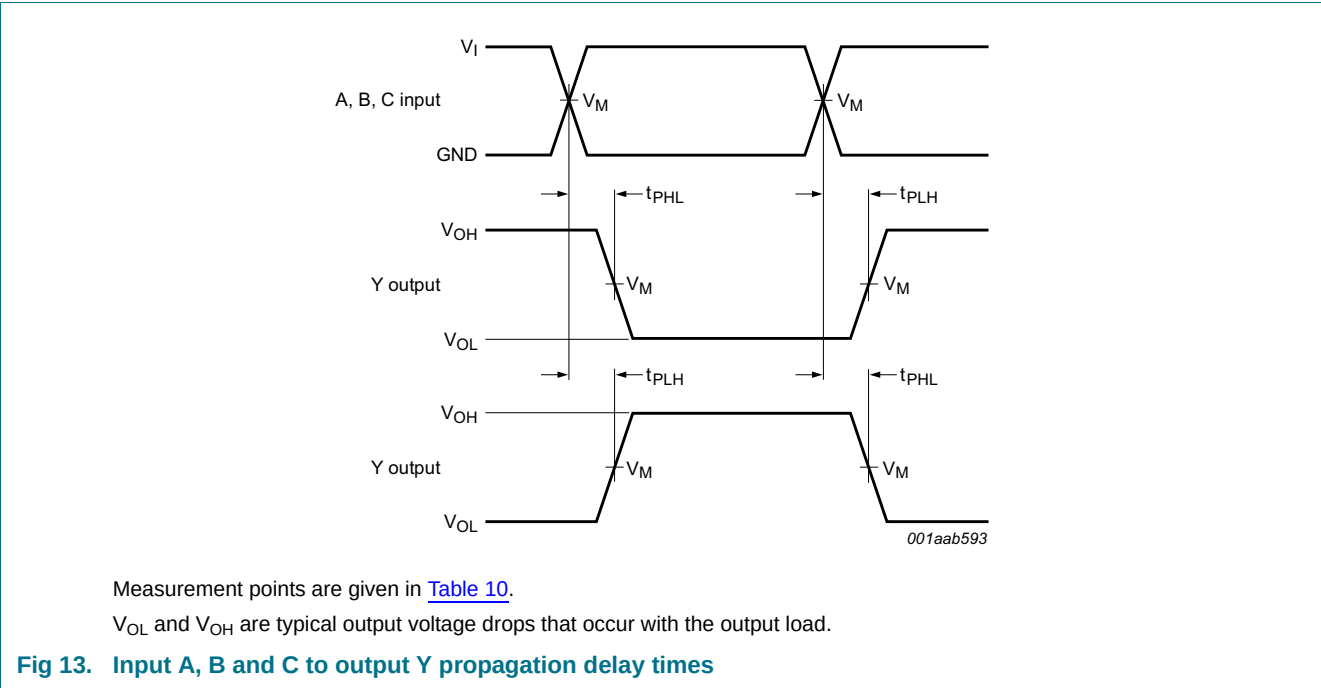
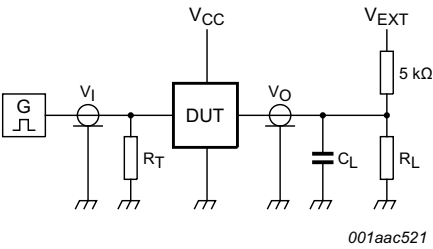


Table 10. Measurement points

Supply voltage	Output	Input		
V_{CC}	V_M	V_M	V_I	$t_r = t_f$
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V_{CC}	$\leq 3.0 \text{ ns}$



Test data is given in [Table 11](#).

Definitions for test circuit:

- R_L = Load resistance.
- C_L = Load capacitance including jig and probe capacitance.
- R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.
- V_{EXT} = External voltage for measuring switching times.

Fig 14. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V_{EXT}		
V_{CC}	C_L	R_L ^[1]	t_{PLH} , t_{PHL}	t_{PZH} , t_{PHZ}	t_{PZL} , t_{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times, $R_L = 5\text{ k}\Omega$. For measuring propagation delays, set-up and hold times, and pulse width, $R_L = 1\text{ M}\Omega$.

13. Transfer characteristics

Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 14](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
V_{T+}	positive-going threshold voltage	see Figure 15 and Figure 16							
		$V_{CC} = 0.8 \text{ V}$	0.30	-	0.60	0.30	0.60	0.62	V
		$V_{CC} = 1.1 \text{ V}$	0.53	-	0.90	0.53	0.90	0.92	V
		$V_{CC} = 1.4 \text{ V}$	0.74	-	1.11	0.74	1.11	1.13	V
		$V_{CC} = 1.65 \text{ V}$	0.91	-	1.29	0.91	1.29	1.31	V
		$V_{CC} = 2.3 \text{ V}$	1.37	-	1.77	1.37	1.77	1.80	V
		$V_{CC} = 3.0 \text{ V}$	1.88	-	2.29	1.88	2.29	2.32	V
V_{T-}	negative-going threshold voltage	see Figure 15 and Figure 16							
		$V_{CC} = 0.8 \text{ V}$	0.10	-	0.60	0.10	0.60	0.60	V
		$V_{CC} = 1.1 \text{ V}$	0.26	-	0.65	0.26	0.65	0.65	V
		$V_{CC} = 1.4 \text{ V}$	0.39	-	0.75	0.39	0.75	0.75	V
		$V_{CC} = 1.65 \text{ V}$	0.47	-	0.84	0.47	0.84	0.84	V
		$V_{CC} = 2.3 \text{ V}$	0.69	-	1.04	0.69	1.04	1.04	V
		$V_{CC} = 3.0 \text{ V}$	0.88	-	1.24	0.88	1.24	1.24	V
V_H	hysteresis voltage	$(V_{T+} - V_{T-})$; see Figure 15 , Figure 16 , Figure 17 and Figure 18							
		$V_{CC} = 0.8 \text{ V}$	0.07	-	0.50	0.07	0.50	0.50	V
		$V_{CC} = 1.1 \text{ V}$	0.08	-	0.46	0.08	0.46	0.46	V
		$V_{CC} = 1.4 \text{ V}$	0.18	-	0.56	0.18	0.56	0.56	V
		$V_{CC} = 1.65 \text{ V}$	0.27	-	0.66	0.27	0.66	0.66	V
		$V_{CC} = 2.3 \text{ V}$	0.53	-	0.92	0.53	0.92	0.92	V
		$V_{CC} = 3.0 \text{ V}$	0.79	-	1.31	0.79	1.31	1.31	V

14. Waveform transfer characteristics

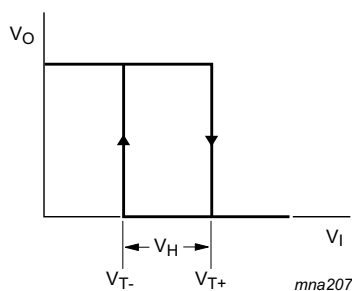
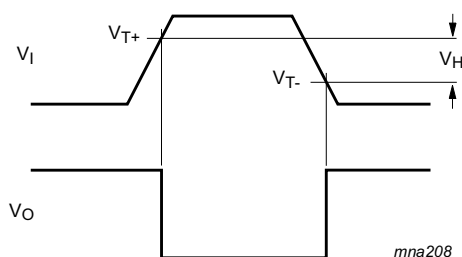


Fig 15. Transfer characteristic



V_{T+} and V_{T-} limits at 70 % and 20 %.

Fig 16. Definition of V_{T+} , V_{T-} , and V_H

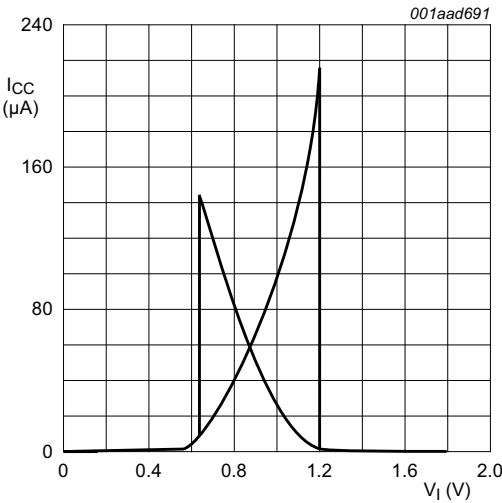


Fig 17. Typical transfer characteristics; $V_{CC} = 1.8\text{ V}$

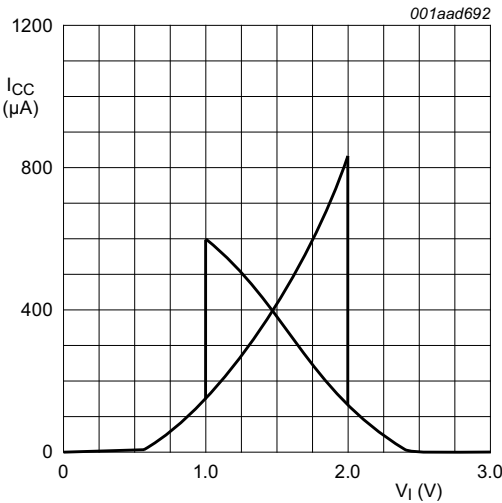


Fig 18. Typical transfer characteristics; $V_{CC} = 3.0\text{ V}$

15. Package outline

Plastic surface-mounted package; 6 leadsSOT363

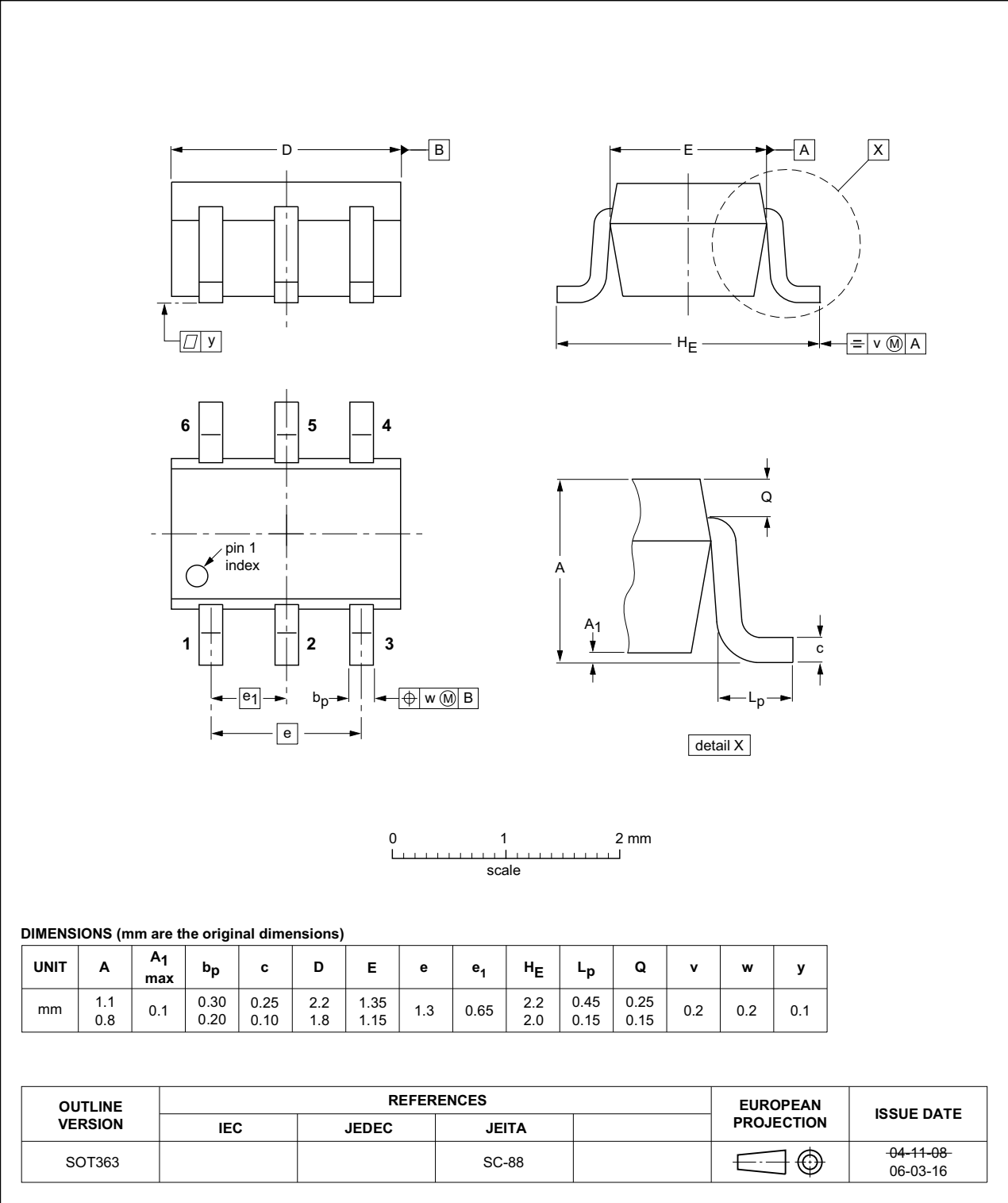


Fig 19. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

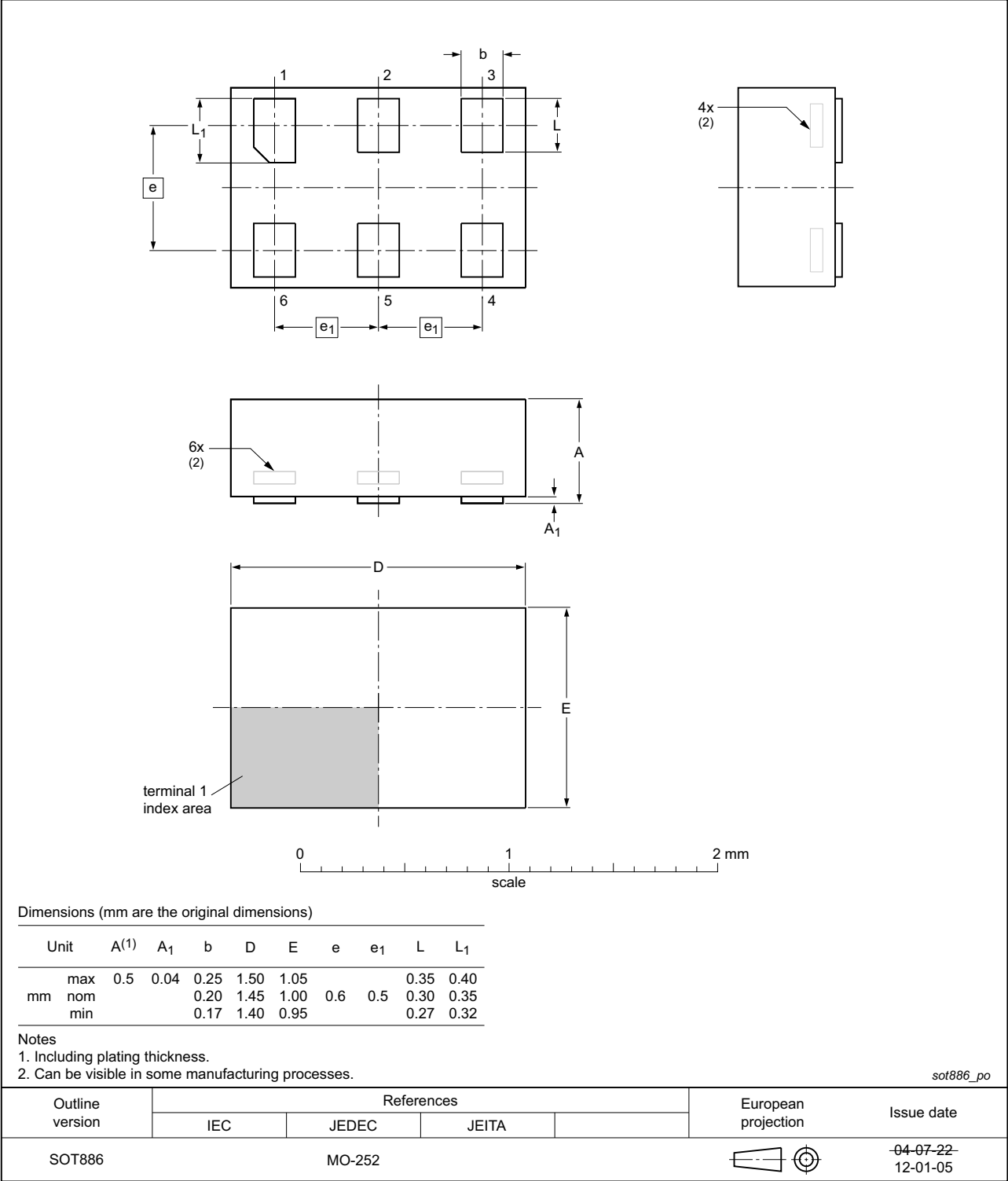


Fig 20. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

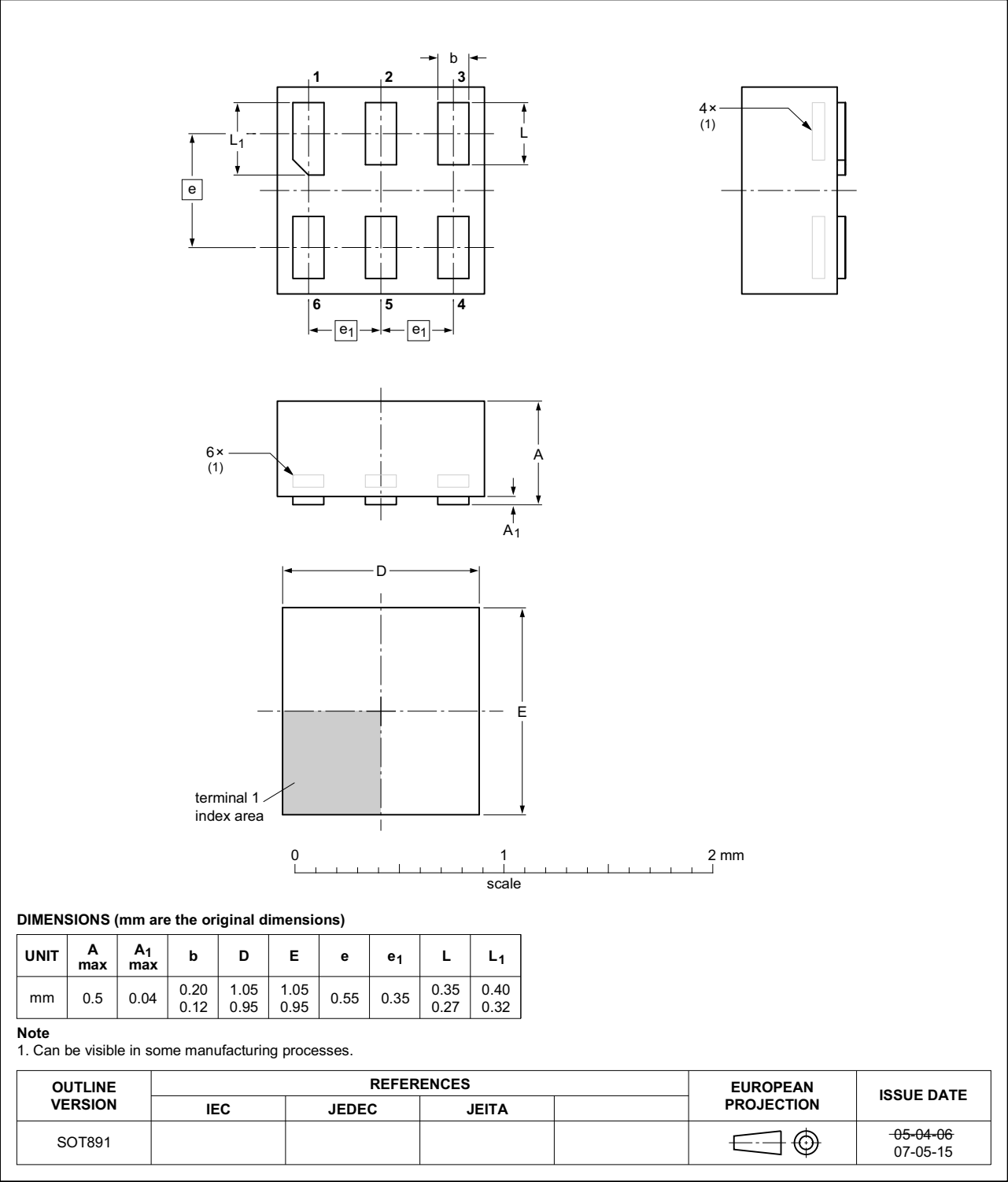


Fig 21. Package outline SOT891 (XSON6)

XSON6: extremely thin small outline package; no leads;
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115

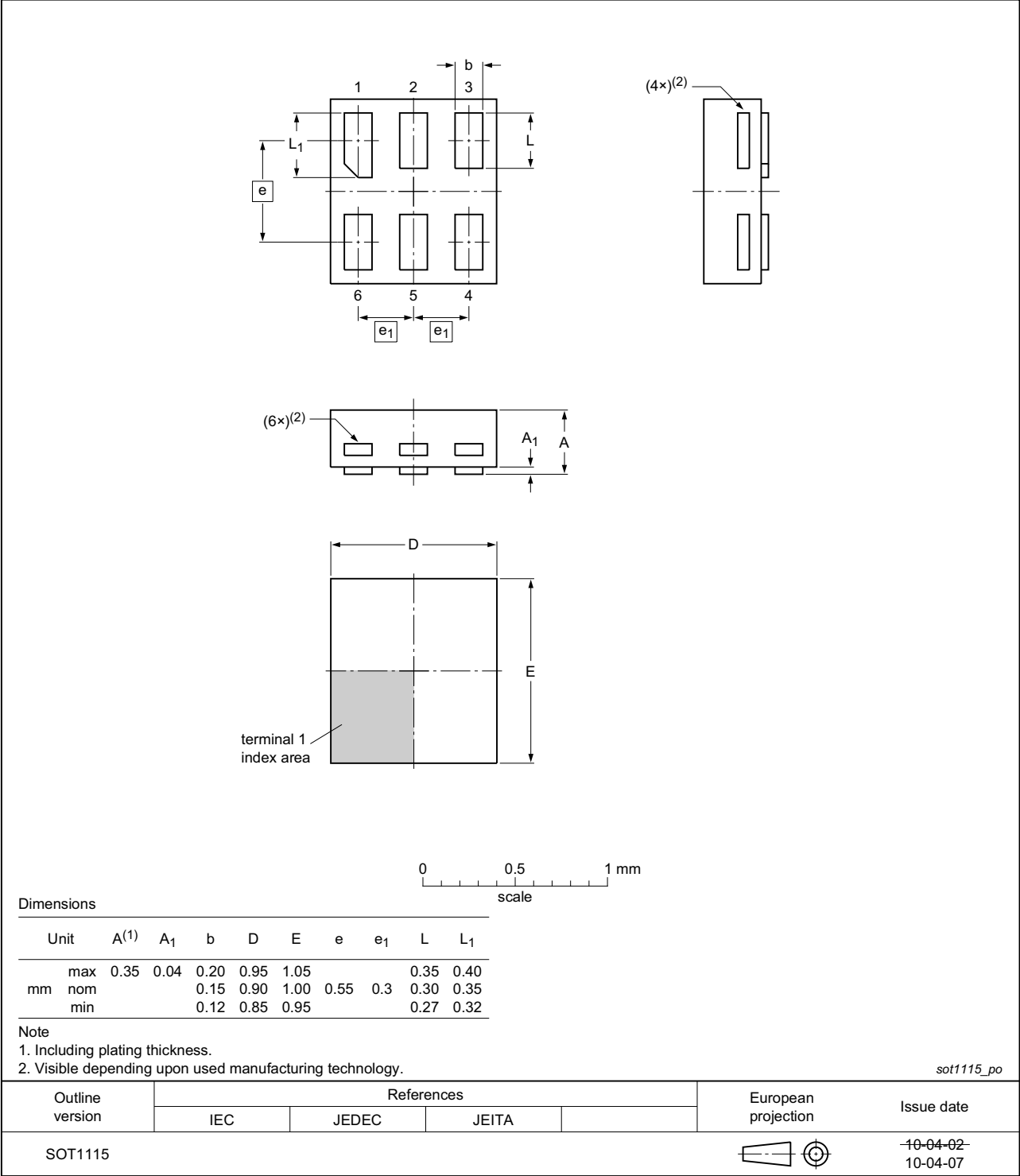


Fig 22. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202

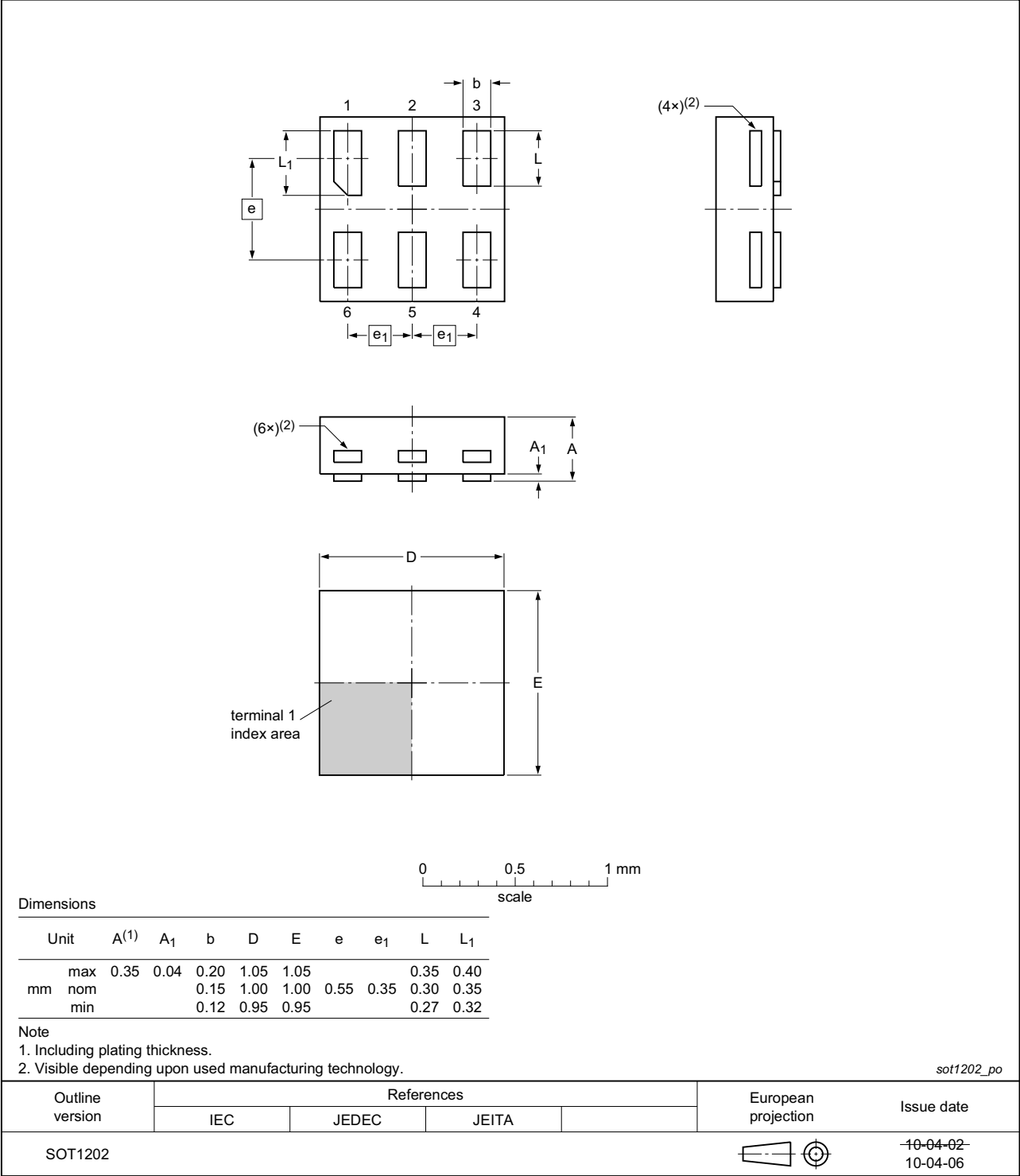


Fig 23. Package outline SOT1202 (XSON6)

X2SON6: plastic thermal enhanced extremely thin small outline package; no leads;
6 terminals; body 1.0 x 0.8 x 0.35 mm

SOT1255

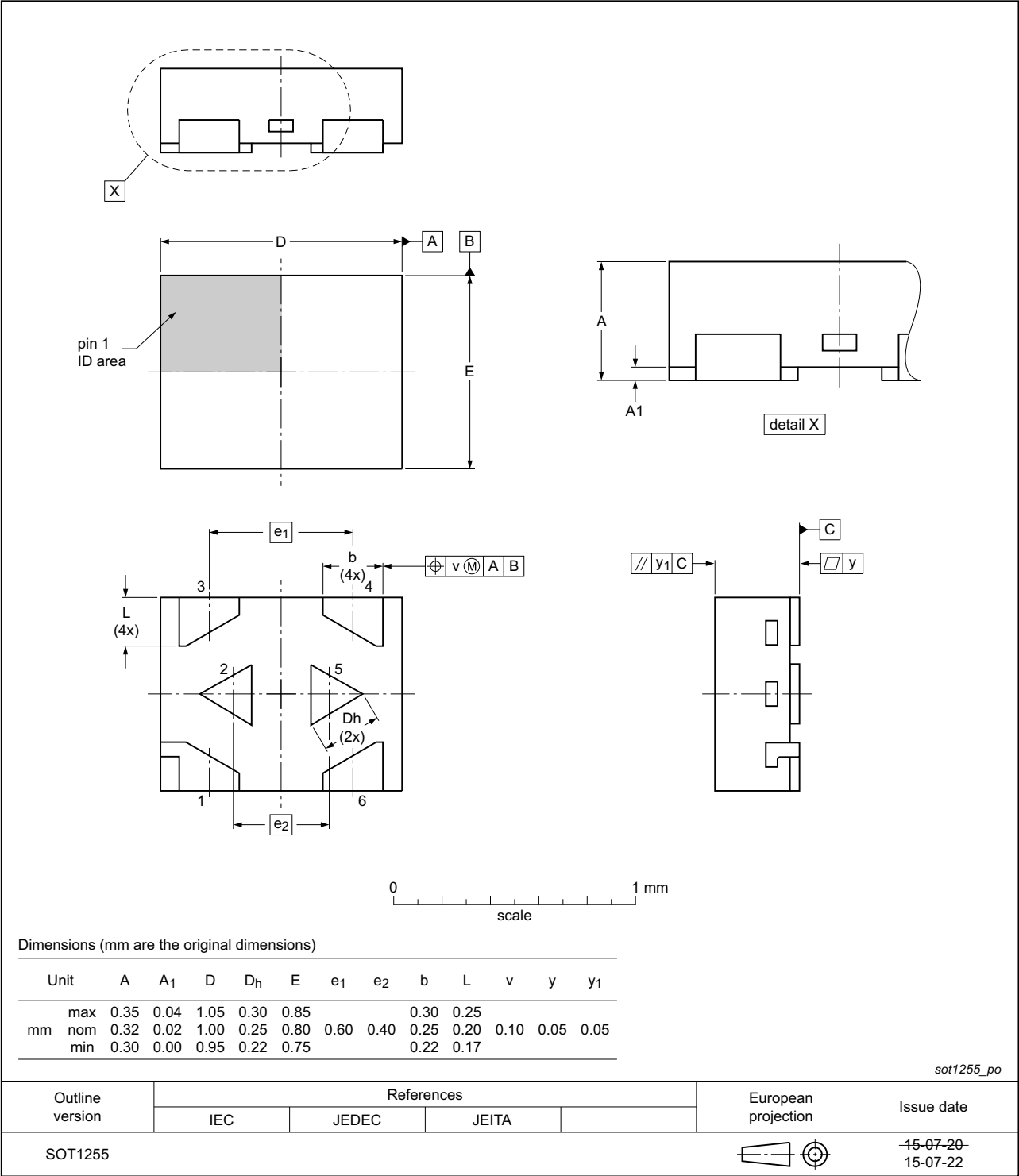


Fig 24. Package outline SOT1255 (X2SON6)

16. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

17. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G57 v.7	20150916	Product data sheet	-	74AUP1G57 v.6
Modifications:	• Added type number 74AUP1G57GX (SOT1255/X2SON6).			
74AUP1G57 v.6	20120815	Product data sheet	-	74AUP1G57 v.5
Modifications:	• Package outline drawing of SOT886 (Figure 20) modified.			
74AUP1G57 v.5	20111125	Product data sheet	-	74AUP1G57 v.4
74AUP1G57 v.4	20100720	Product data sheet	-	74AUP1G57 v.3
74AUP1G57 v.3	20090622	Product data sheet	-	74AUP1G57 v.2
74AUP1G57 v.2	20090323	Product data sheet	-	74AUP1G57 v.1
74AUP1G57 v.1	20061123	Product data sheet	-	-

18. Legal information

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Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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20. Contents

1	General description	1
2	Features and benefits	1
3	Ordering information	2
4	Marking	2
5	Functional diagram	2
6	Pinning information	3
6.1	Pinning	3
6.2	Pin description	3
7	Functional description	4
7.1	Logic configurations	4
8	Limiting values	5
9	Recommended operating conditions	6
10	Static characteristics	6
11	Dynamic characteristics	9
12	Waveforms	11
13	Transfer characteristics	13
14	Waveform transfer characteristics	13
15	Package outline	15
16	Abbreviations	21
17	Revision history	21
18	Legal information	22
18.1	Data sheet status	22
18.2	Definitions	22
18.3	Disclaimers	22
18.4	Trademarks	23
19	Contact information	23
20	Contents	24

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